

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Report No: CCISE190704609

FCC REPORT

Applicant: PAX Technology Limited

Address of Applicant: Room 2416, 24/F., Sun Hung Kai Centre, 30 Harbour Road,

Wanchai, Hong Kong

Equipment Under Test (EUT)

Product Name: POS Terminal

Model No.: IM30

Trade mark: PAX

FCC ID: V5PIM304GBW

FCC CFR Title 47 Part 2

FCC CFR Title 47 Part 22 Subpart H

FCC CFR Title 47 Part 24 Subpart E

Applicable standards: FCC CFR Title 47 Part 27 Subpart L

FCC CFR Title 47 Part 27 Subpart F FCC CFR Title 47 Part 27 Subpart H FCC CFR Title 47 Part 27 Subpart N

Date of sample receipt: 11 Jul., 2019

Date of Test: 11 Jul., to 19 Aug., 2019

Date of report issued: 20 Aug., 2019

Test Result: PASS*

Authorized Signature:



Bruce Zhang Laboratory Manager

This report details the results of the testing carried out on one sample. The results contained in this test report do not relate to other samples of the same product and does not permit the use of the CCIS product certification mark. The manufacturer should ensure that all products in series production are in conformity with the product sample detailed in this report.

This report may only be reproduced and distributed in full. If the product in this report is used in any configuration other than that detailed in the report, the manufacturer must ensure the new system complies with all relevant standards.

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^{*}In the configuration tested, the EUT complied with the standards specified above.





2. Version

Version No.	Date	Description
00	20 Aug., 2019	Original

Mike. DU

Test Engineer Tested by: Date: 20 Aug., 2019

Winner Thang Reviewed by: Date: 20 Aug., 2019

Project Engineer



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4. Test Summary

Test Items	Section in CFR 47	Result
RF Exposure (SAR)	Part 1.1307	Passed
Tr Exposure (OAT)	Part 2.1093	(Please refer to MPE Report)
	Part 2.1046	
	Part 22.913 (a)(5)	
	Part 24.232 (c)	
RF Output Power	Part 27.50 (c)(10)	Pass*
	Part 27.50 (d)(4)	
	Part 27.50 (h)(2)	
	Part 27.50 (b)(10)	
Dook to Average Detic	Part 24.232 (d)	Door*
Peak-to-Average Ratio	Part 27.50(d)(5)	Pass*
Modulation Characteristics	Part 2.1047	Pass*
	Part 2.1049	
	Part 22.917(b)	
00% \$ 26 dB Occupied Bandwidth	Part 24.238(b)	Pass*
99% & -26 dB Occupied Bandwidth	Part 27.53(g)	F d55
	Part 27.53(h)	
	Part 27.53(c)(2)(4)	
	Part 2.1053	
	Part 22.917(a)	
Out of band emission at antenna terminals	Part 24.238 (a)	Pass*
Out of band emission at antenna terminals	Part 27.53 (g)	r ass
	Part 27.53 (h)	
	Part 27.53(c)(2)	
	Part 22.917(a)	
	Part 24.238 (a)	
Field strength of spurious radiation	Part 27.53 (g)	Pass
	Part 27.53 (h)	
	Part 27.53(c)(2)(4)	
	Part 22.355	
Fraguency stability valtemperature	Part 24.235	Door*
Frequency stability vs. temperature	Part 27.54	Pass*
	Part 2.1055(a)(1)(b)	
	Part 22.355	
Fraguency stability via valtage	Part 24.235	Door*
Frequency stability vs. voltage	Part 27.54	Pass*
	Part 2.1055(d)(2)	
Pass: The EUT complies with the essential requ	irements in the standard.	

Pass*: please refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.



5. General Information

5.1 Client Information

Applicant:	PAX Technology Limited
Address:	Room 2416, 24/F., Sun Hung Kai Centre, 30 Harbour Road, Wanchai, Hong Kong
Manufacturer:	PAX Computer Technology(Shenzhen) Co. Ltd.
Address:	401-402 No.3 Building, Software Park, Nanshan district, Shenzhen, Guangdong, P.R.C.

5.2 General Description of E.U.T.

Product Name:	POS Terminal	
Model No.:	IM30	
Operation Frequency range:	LTE Band 2: TX: 1850MHz-1910MHz, RX: 1930MHz-1990MHz LTE Band 4: TX: 1710MHz-1755MHz, RX: 2110MHz-2155MHz LTE Band 5: 824MHz-849MHz, RX: 869MHz-894MHz LTE Band 12: TX: 699MHz-716MHz, RX: 729MHz-746MHz LTE Band 13: TX: 777MHz-787MHz, RX: 746MHz-756MHz LTE Band 17: TX: 704MHz-716MHz, RX: 734MHz-746MHz LTE Band 66: TX: 1710MHz-1780MHz, RX: 2110MHz-2200MHz LTE Band 71: TX: 663MHz-698MHz, RX: 617MHz-652MHz	
Modulation type:	QPSK, 16QAM	
Antenna type:	Internal Antenna	
Antenna gain:	LTE Band 2: 3.4dBi LTE Band 4: 3.4dBi LTE Band 5: 3.4dBi LTE Band 12: 3.4dBi LTE Band 13: 3.4dBi LTE Band 17: 3.4dBi LTE Band 66: 3.4dBi LTE Band 71: 3.4dBi	
Power supply:	DC 12V-48V	
Test Sample Condition:	The applicant provided engineering samples for staying in continuously transmitting for testing.	





Operation Frequency List:

Operation Frequency List:	2 (4 4MH -)	LTE Band 2 (3MHz)	
LTE Band 2			_ `
Channel	Frequency (MHz)	Channel	Frequency (MHz)
18607	1850.70	18615	1851.50
18608	1850.80	18616	1851.60
••••			
18899	1879.90	18899	1879.90
18900	1880.00	18900	1880.00
18901	1880.10	18901	1880.10
	•••		•••
19193	1909.20	19185	1908.40
19194	1909.30	19186	1908.50
LTE Band	2 (5MHz)	LTE Band	2 (10MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
18625	1852.50	18650	1855.00
18626	1852.60	18651	1855.10
18899	1879.90	18899	1879.90
18900	1880.00	18900	1880.00
18901	1880.10	18901	1880.10
	•••		
19175	1907.40	19150	1904.90
19176	1907.50	19151	1905.00
LTE Band	2 (15MHz)	LTE Band 2 (20MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
18675	1857.50	18700	1860.00
18676	1857.60	18701	1860.10
18899	1879.90	18899	1879.90
18900	1880.00	18900	1880.00
18901	1880.10	18901	1880.10
19125	1902.40	19100	1899.90
19126	1902.50	19101	1900.00



LTE Band 4 (1.4MHz)		LTE Band 4 (3MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
19957	1710.70	19965	1711.50
19958	1710.80	19966	1711.60
20174	1732.40	20174	1732.40
20175	1732.50	20175	1732.50
20176	1732.60	20176	1732.60
20392	1754.20	20384	1753.40
20393	1754.30	20385	1753.50
LTE Ba	nd 4 (5MHz)	LTE Ban	d 4 (10MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
19975	1712.50	20000	1715.00
19976	1712.60	20001	1715.10
20174	1732.40	20174	1732.40
20175	1732.50	20175	1732.50
20176	1732.60	20176	1732.60
20374	1752.40	20349	1749.90
20375	1752.50	20350	1750.00
LTE Bar	nd 4 (15MHz)	LTE Ban	d 4 (20MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
20025	1717.50	20050	1720.00
20026	1717.60	20051	1720.10
20174	1732.40	20174	1732.40
20175	1732.50	20175	1732.50
20176	1732.60	20176	1732.60
20324	1747.40	20299	1744.90
20325	1747.50	20300	1745.00



LTE Band 5 (1.4MHz)		LTE Band 5 (3MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
20407	824.70	20415	825.50
20408	824.80	20416	825.60
20524	836.40	20524	836.40
20525	836.50	20525	836.50
20526	836.60	20526	836.60
20642	848.20	20634	847.40
20643	848.30	20635	847.50
LTE Band	d 5 (5MHz)	LTE Band 5 (10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
20425	826.50	20450	829.00
20426	826.60	20451	829.10
20524	836.40	20524	836.40
20525	836.50	20525	836.50
20526	836.60	20526	836.60
20624	846.40	20599	839.90
20625	846.50	20600	844.00

LTE Band 12 (1.4MHz)		LTE Band 12 (3MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
23017	699.70	23025	700.50
23756	699.80	23026	700.60
23094	707.40	23094	707.40
23095	707.50	23095	707.50
23096	707.60	23096	707.60
23172	715.20	23164	714.40
23173	715.30	23165	714.50
LTE Band	12 (5MHz)	LTE Band 12 (10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
23035	701.50	23060	704.00
23036	701.60	23061	704.10
23094	707.40	23094	707.40
23095	707.50	23095	707.50
23096	707.60	23096	707.60
23154	713.40	23129	710.90
23155	713.50	23130	711.00



LTE Band 13 (5MHz)		LTE Band 13 (10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
23205	779.50	23230	782
	••••		
23230	782.00		
23255	784.50		

LTE Band 17 (5MHz)		LTE Band 17 (10MHz)	
Channel	Frequency (MHz)	Channel	Frequency (MHz)
23755	706.50	23780	709.00
23756	706.60	23781	709.10
23789	709.90	23789	709.90
23790	710.00	23790	710.00
23791	710.10	23791	710.10
	•••		
23824	713.40	23799	710.90
23825	713.50	23800	711.00



LTE Band 66 (1.4MHz)		LTE Band	66 (3MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
131979	1710.70	131987	1711.50
131980	1710.80	131988	1711.60
132321	1744.90	132321	1744.90
132322	1745.00	132322	1745.00
132323	1745.10	132323	1745.10
132664	1779.20	132656	1778.40
132665	1779.30	132657	1778.50
LTE Band	66 (5MHz)	LTE Band 6	66 (10MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
131997	1712.50	132022	1715.00
131998	1712.60	132023	1715.10
			••••
132321	1744.90	132321	1744.90
132322	1745.00	132322	1745.00
132323	1745.10	132323	1745.10
			•••
136246	1777.40	132621	1774.90
136247	1777.50	132622	1775.00
LTE Band	LTE Band 66 (15MHz)		66 (20MHz)
Channel	Frequency (MHz)	Channel	Frequency (MHz)
18675	1857.50	18700	1860.00
18676	1857.60	18701	1860.10
132321	1744.90	132321	1744.90
132322	1745.00	132322	1745.00
132323	1745.10	132323	1745.10
19125	1902.40	19100	1899.90
19126	1902.50	19101	1900.00



I TE Bar	nd 71 (5MHz)	LTE Band 71 (10MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
134122	673.00	133872	670.50	
134123	673.10	133873	670.60	
133296	680.40	133296	680.40	
133297	680.50	133297	680.50	
133298	680.60	133298	680.60	
133371	687.90	133396	690.40	
133372	688.00	133397	690.50	
LTE Ban	d 71 (15MHz)	LTE Band 71 (20MHz)		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
133622	668.00	133372	665.50	
133623	668.10	133371	655.60	
133296	680.40	133296	680.40	
133297	680.50	133297	680.50	
133298	680.60	133298	680.60	
133421	692.90	133446	695.40	
133422	693.00	133447	695.50	



Regards to the operating frequency range, the lowest frequency, the middle frequency, and the highest frequency of channel were selected to perform the test, and the selected channels as below:

LTE Band 2 (1.4MHz)			LTE Band 2 (3MHz)		
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	18607	1850.70	Lowest channel	18615	1851.50
Middle channel	18900	1880.00	Middle channel	18900	1880.00
Highest channel	19193	1909.30	Highest channel	19185	1908.50
LTE	E Band 2 (5MF	Hz)	LTE	Band 2 (10MF	Hz)
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	18625	1852.50	Lowest channel	18650	1855.00
Middle channel	18900	1880.00	Middle channel	18900	1880.00
Highest channel	19175	1907.50	Highest channel	19150	1905.00
LTE	Band 2 (15M	Hz)	LTE Band 2 (20MHz)		
Channe	I	Frequency (MHz)	Channel Freque		Frequency (MHz)
Lowest channel	18675	1857.50	Lowest channel	18700	1860.00
Middle channel	18900	1880.00	Middle channel	18900	1880.00
Highest channel	19125	1902.50	Highest channel	19100	1900.00

LTE Band 4 (1.4MHz)			LTE Band 4 (3MHz)		
Channel	:	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	19957	1710.70	Lowest channel	19965	1711.50
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20393	1754.30	Highest channel	20385	1753.50
LTE	Band 4 (5Ml	Hz)	LTE	Band 4 (10MF	łz)
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	19975	1712.50	Lowest channel	20000	1715.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20375	1752.50	Highest channel	20350	1750.00
LTE	Band 4 (15M	Hz)	LTE Band 4 (20MHz)		
Channe	I	Frequency (MHz)	c) Channel Fred		Frequency (MHz)
Lowest channel	20025	1717.50	Lowest channel	20050	1720.00
Middle channel	20175	1732.50	Middle channel	20175	1732.50
Highest channel	20325	1747.50	Highest channel	20300	1745.00

LTE Band 5 (1.4MHz)			LTE Band 5 (3MHz)		
Channe	l:	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	20407	824.70	Lowest channel	20415	825.50
Middle channel	20525	836.50	Middle channel	20525	836.50
Highest channel	20643	848.30	Highest channel	20635	847.50
LTE	E Band 5 (5MF	Hz)	LTE Band 5 (10MHz)		
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	20425	826.50	Lowest channel	20450	829.00
Middle channel	20525	836.50	Middle channel	20525	836.50
Highest channel	20625	846.50	Highest channel	20600	844.00





LTE Band 12(1.4MHz)			LTE Band 12(3MHz)		
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	23017	699.70	Lowest channel	23025	700.50
Middle channel	23095	707.50	Middle channel	23095	707.50
Highest channel	23173	715.30	Highest channel	23165	714.50
LTE	Band 12(5MI	Hz)	LTE Band 12(10MHz)		
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	23035	701.50	Lowest channel	23060	704.00
Middle channel	23095	707.50	Middle channel	23095	707.50
Highest channel	23155	713.50	Highest channel	23130	711.00

LTE Band 13(5MHz)			LTE Band 13(10MHz)		
Channe	l	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	23205	779.5	Lowest channel		
Middle channel	23230	782.0	Middle channel	23230	782.00
Highest channel	23255	784.5	Highest channel		

LTE Band 17(5MHz)			LTE Band 17(10MHz)		
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	23755	706.50	Lowest channel	23780	709.00
Middle channel	23790	710.00	Middle channel	23790	710.00
Highest channel	23825	713.50	Highest channel	23800	711.00

LTE Band 66 (1.4MHz)			LTE	Band 66 (3MH	Hz)
Channe	I	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	131979	1710.7	Lowest channel	131987	1711.5
Middle channel	132322	1745.0	Middle channel	132322	1745.0
Highest channel	132665	1779.3	Highest channel	132657	1778.5
LTE	Band 66 (5M	Hz)	LTE Band 66 (10MHz)		
Channe	I	Frequency (MHz)	Channel Fre		Frequency (MHz)
Lowest channel	131997	1712.5	Lowest channel	132022	1715.0
Middle channel	132322	1745.5	Middle channel	132322	1745.0
Highest channel	132647	1777.5	Highest channel	132622	1775.0
LTE	Band 66 (15M	1Hz)	LTE Band 66 (20MHz)		Hz)
Channe	I	Frequency (MHz)	MHz) Channel		Frequency (MHz)
Lowest channel	132047	1717.5	Lowest channel	132072	1720.0
Middle channel	132322	1745.0	Middle channel	132322	1745.0
Highest channel	132597	1772.5	Highest channel	132572	1770.0





LTE Band 71 (5MHz)			LTE I	Band 71 (10M	Hz)
Channe	l	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	134122	673.0	Lowest channel	133872	670.5
Middle channel	133297	680.5	Middle channel	133297	680.5
Highest channel	133372	688.0	Highest channel	133397	690.5
LTE	Band 71 (15M	1Hz)	LTE Band 71 (20MHz)		
Channe	d	Frequency (MHz)	Channel		Frequency (MHz)
Lowest channel	133622	668.0	Lowest channel	133372	665.5
Middle channel	133297	680.5	Middle channel	133297	680.5
Highest channel	133422	693.0	Highest channel	133447	695.5

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5.3 Test environment and mode

Operating Environment	Operating Environment:			
Temperature:	Normal: 15° C ~ 35° C, Extreme: -30° C ~ $+50^{\circ}$ C			
Humidity:	20 % ~ 75 % RH			
Atmospheric Pressure:	1008 mbar			
Voltage:	Nominal: 24Vdc, Extreme: Low 10.2Vdc, High 52.8Vdc			
Test mode:				
LTE QPSK mode	Keep the EUT communication with simulated station in QPSK mode			
LTE 16-QAM mode	Keep the EUT communication with simulated station in 16-QAM mode			

Remark: The EUT has been tested under continuous transmitting mode. Channel Low, Mid and High for each type band with rated data rate were chosen for full testing. The field strength of spurious radiation emission was measured as EUT stand-up position (H mode) and lie down position (E1, E2 mode) for these modes with power adaptor, earphone and Data cable. Just the worst case position (H mode) shown in report.

5.4 Description of Support Units

Test Equipment	Manufacturer	Model No.	Serial No.
Simulated Station	Anritsu	MT8820C	6201026545

5.5 Measurement Uncertainty

	-
Parameters	Expanded Uncertainty
Radiated Emission (9kHz ~ 30MHz)	±3.12 dB (k=2)
Radiated Emission (30MHz ~ 1000MHz)	±4.32 dB (k=2)
Radiated Emission (1GHz ~ 18GHz)	±5.38 dB (k=2)
Radiated Emission (18GHz ~ 40GHz)	±3.36 dB (k=2)

5.6 Related Submittal(s) / Grant (s)

This is an original grant, no related submittals and grants.

5.7 Laboratory Facility

The test facility is recognized, certified, or accredited by the following organizations:

• FCC - Designation No.: CN1211

Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been accredited as a testing laboratory by FCC (Federal Communications Commission). The test firm Registration No. is 727551.

ISED – CAB identifier.: CN0021

The 3m Semi-anechoic chamber of Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been Registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 10106A-1.

CNAS - Registration No.: CNAS L6048

Shenzhen Zhongjian Nanfang Testing Co., Ltd. is accredited to ISO/IEC 17025:2005 General Requirements for the Competence of Testing and Calibration laboratories for the competence of testing. The Registration No. is CNAS L6048.

A2LA - Registration No.: 4346.01

This laboratory is accredited in accordance with the recognized International Standard ISO/IEC 17025:2005 General requirements for the competence of testing and calibration laboratories. The test scope can be found as below link: https://portal.a2la.org/scopepdf/4346-01.pdf

5.8 Laboratory Location

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Address: No. B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

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Bao'an District, Shenzhen, Guangdong, China Telephone: +86 (0) 755 23118282 Fax: +86 (0) 755 23116366





5.9 Test Instruments list

Test Equipment	Manufacturer	Model No.	Serial No.	Cal. Date (mm-dd-yy)	Cal. Due date (mm-dd-yy)
3m SAC	SAEMC	9m*6m*6m	966	07-22-2017	07-21-2020
BiConiLog Antenna	SCHWARZBECK	VULB9163	497	03-18-2019	03-17-2020
Biconical Antenna	SCHWARZBECK	VUBA9117	359	06-22-2017	06-21-2020
Horn Antenna	SCHWARZBECK	BBHA9120D	916	03-18-2019	03-17-2020
Horn Antenna	SCHWARZBECK	BBHA9120D	1805	06-22-2017	06-21-2020
Horn Antenna	SCHWARZBECK	BBHA 9170	BBHA9170582	11-21-2018	11-20-2019
EMI Test Software	AUDIX	E3	١	/ersion: 6.110919	b
Pre-amplifier	HP	8447D	2944A09358	03-18-2019	03-17-2020
Pre-amplifier	CD	PAP-1G18	11804	03-18-2019	03-17-2020
Spectrum analyzer	Rohde & Schwarz	FSP30	101454	03-18-2019	03-17-2020
EMI Test Receiver	Rohde & Schwarz	ESRP7	101070	03-18-2019	03-17-2020
Spectrum Analyzer	Agilent	N9020A	MY50510123	10-29-2018	10-28-2019
Signal Generator	Rohde & Schwarz	SMX	835454/016	03-18-2019	03-17-2020
Signal Generator	R&S	SMR20	1008100050	03-18-2019	03-17-2020
RF Switch Unit	MWRFTEST	MW200	N/A	N/A	N/A
Test Software	MWRFTEST	MTS8200		Version: 2.0.0.0	
Cable	ZDECL	Z108-NJ-NJ-81	1608458	03-18-2019	03-17-2020
Cable	MICRO-COAX	MFR64639	K10742-5	03-18-2019	03-17-2020
Cable	SUHNER	SUCOFLEX100	58193/4PE	03-18-2019	03-17-2020
DC Power Supply	XinNuoEr	WYK-10020K	1409050110020	10-31-2018	10-30-2019
Temperature Humidity Chamber	HengPu	HPGDS-500	20140828008	09-24-2018	09-23-2019
Simulated Station	Rohde & Schwarz	CMMF00	140402	07-16-2018	07-15-2019
Simulated Station	Konde & Schwarz	CMW500	140493	07-16-2019	07-15-2020



6. Test results

6.1 Conducted Output Power, ERP and EIRP

Test Requirement:	Part 22.913(a)(5), Part 24.232(c), part 27.50(c)(10), Part 27.50(d)(4), Part 27.50 (h)(2), Part 27.50 (b)(10)
Test Method:	ANSI/TIA-603-D 2010
Limit:	LTE Band 2: 2W, LTE Band 4: 1W, LTE Band 5: 7W, LTE Band 12: 3W, LTE Band 17: 3W, LTE Band 13: 3W, LTE Band 66: 1W, LTE Band 71: 3W
Test Setup:	System simulator ATT EUT
Test Procedure:	The transmitter output was connected to a calibrated attenuator, the other end of which was connected to the CMW500. Transmitter output power was read off in dBm.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B. Only retest ERP and EIRP





Measurement Data:

LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. EIRP(dBm)	EIRP Limit (dBm)
	1.4	QPSK	23.16	26.56	
	1.4	16QAM	22.13	25.53	
	3	QPSK	23.03	26.43	
2	3	16QAM	22.28	25.68	
	5	QPSK	23.22	26.62	33
		16QAM	21.88	25.28	
	10	QPSK	23.17	26.57	
		16QAM	22.30	25.70	
		QPSK	23.22	26.62	
		16QAM	22.35	25.75	
		QPSK	23.31	26.71	
	20	16QAM	22.13	25.53	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi.

1.4 QPSK 22.93 26.33 16QAM 21.98 25.38 QPSK 23.00 26.40 16QAM 21.68 25.08 QPSK 23.00 26.40 5 QPSK 23.00 26.40 16QAM 21.67 25.07 QPSK 23.03 26.43 10 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46	LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. EIRP(dBm)	EIRP Limit (dBm)
4 16QAM 21.98 25.38 QPSK 23.00 26.40 16QAM 21.68 25.08 QPSK 23.00 26.40 16QAM 21.67 25.07 QPSK 23.03 26.43 10 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46		1 1	QPSK	22.93	26.33	
4 16QAM 21.68 25.08 QPSK 23.00 26.40 16QAM 21.67 25.07 QPSK 23.03 26.43 10 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46		1.4	16QAM	21.98	25.38	
4 QPSK 23.00 26.40 16QAM 21.67 25.07 QPSK 23.03 26.43 10 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46		2	QPSK	23.00	26.40	
4 16QAM 21.67 25.07 30 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46		5	16QAM	21.68	25.08	
4 16QAM 21.67 25.07 30 QPSK 23.03 26.43 16QAM 22.09 25.49 QPSK 23.06 26.46			QPSK	23.00	26.40	
10 QPSK 23.03 26.43 16QAM 22.09 25.49 OPSK 23.06 26.46	4		16QAM	21.67	25.07	30
16QAM 22.09 25.49 OPSK 23.06 26.46	4		QPSK	23.03	26.43	
QPSK 23.06 26.46			16QAM	22.09	25.49	
			45 QPSK	23.06	26.46	
15 16QAM 21.70 25.10			16QAM	21.70	25.10	
QPSK 23.07 26.47		20	QPSK	23.07	23.07 26.47	
20 16QAM 21.89 25.29		20	16QAM	21.89	25.29	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG801914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi.

LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. ERP(dBm)	ERP Limit (dBm)
	1.4	QPSK	22.82	24.07	
	1.4	16QAM	21.89	23.14	
_	2	QPSK	22.76	24.01	
	3	16QAM	21.43	22.68	38.45
5	E	QPSK	22.75	24.00	30.43
	5	16QAM	21.88	23.13	
	10	QPSK	22.86	24.11	
	10	16QAM	21.71	22.96	1

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi. ERP (dBm) = EIRP (dBm) - 2.15 (dB).





LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. ERP(dBm)	ERP Limit (dBm)
	1.4	QPSK	23.23	23.23 24.48	
	1.4	16QAM	22.29	23.54	
3	3	QPSK	23.28	24.53	34.77
12	S	16QAM	22.06	23.31	
	5	QPSK	23.24	24.49	
	5	16QAM	21.93	23.18	
	10	QPSK	23.54	24.79	
	10	16QAM	22.56	23.81	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi. ERP (dBm) = EIRP (dBm) - 2.15 (dB).

LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. ERP(dBm)	EIRP Limit (dBm)
	_	QPSK	23.20	24.45	
13	3	16QAM	22.04	23.29	34.77
13	10	QPSK	23.24	24.49	34.77
	10	16QAM	22.06	23.31	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi. ERP (dBm) = EIRP (dBm) - 2.15 (dB).

LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. ERP(dBm)	ERP Limit (dBm)
	E	QPSK	23.48	24.73	
17	5	16QAM	22.51	23.76	34.77
17	10	QPSK	23.50	24.75	34.77
	10	16QAM	22.48	23.73	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi. ERP (dBm) = EIRP (dBm) - 2.15 (dB).

LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. EIRP(dBm)	EIRP Limit (dBm)
	1.4	QPSK	23.36	26.76	
	1.4	16QAM	22.43	25.83	
	3	QPSK	23.43	26.83	
	5	16QAM	22.41	25.81	
		QPSK	23.26	26.66	
66		16QAM	22.21	25.61	30
00		QPSK	23.36	26.76	
	10	16QAM	22.75	26.15	
	15	QPSK	23.18	26.58	
		16QAM	22.16	25.56	
	20	QPSK	23.63	27.03	
	20	16QAM	22.37	25.77	

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi.





LTE Band	Bandwidth (MHz)	Modulation	Max Conducted Output Power(dBm)	Max. ERP(dBm)	ERP Limit (dBm)
	5	QPSK	23.42	24.67	
	5	16QAM	22.57	23.82	
1	10	QPSK	23.71	24.96	34.77
71	10	16QAM	22.49	23.74	
/ 1	15	QPSK	23.65	24.90	
	15	16QAM	22.36	23.61	
	20	QPSK	23.87	25.12	
	20	16QAM	22.99	24.24	1

Note: Max Conducted Output Power Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B EIRP (dBm) = Average power (dBm) + Antenna Gain (dBi), Antenna Gain=3.4 dBi. ERP (dBm) = EIRP (dBm) - 2.15 (dB)



6.2 Peak-to-Average Ratio

Test Requirement:	Part 24.232 (d), Part 27.50(d)(5)
Test Method:	ANSI C63.26-2015
Limit:	The peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.
Test Setup:	System simulator Splitter ATT EUT Spectrum Analyzer
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. Set the CCDF option in spectrum analyzer, RBW ≥ OBW, Set the EUT working in highest power level, measured and recorded the 0.1% as PAPR level. Repeat step 1~3 at other frequency and modulations.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.



6.3 Occupy Bandwidth

Test Requirement:	Part 22.917(b), Part 24.238(b), Part 27.53(g), Part 27.53(h), Part 27.53(c)(2)(4)
Test Method:	ANSI/TIA-603-D 2010
Test Setup:	
	System simulator Splitter ATT EUT Spectrum Analyzer
Test Procedure:	 The EUT's output RF connector was connected with a short cable to the spectrum analyzer RBW was set to about 1% ~ 5% of emission BW, VBW= 3 times RBW. -26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.



6.4 Out of band emission at antenna terminals

Test Requirement:	Part 22.917(a), Part 24.238 (a), Part 27.53 (g), Part 27.53 (h), Part 27.53(c)(2)
Test Method:	ANSI/TIA-603-D 2010
Limit:	LTE Band 2 & 4 & 5 & 12 & 13 & 17 & 66 & 71: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 log ₁₀ (P) dB (-13 dBm).
Test Setup:	System simulator Spectrum Analyzer
Test Procedure:	The RF output of the transceiver was connected to a spectrum
rest i rocedure.	 analyzer through appropriate attenuation. The resolution bandwidth of the spectrum analyzer was set at 100 kHz when below 1GHz, 1MHz when above 1 GHz; sufficient scans were taken to show the out of band Emissions if any up to 10th harmonic. For the out of band: Set the RBW=100 kHz, VBW=300 kHz when below 1 GHz, RBW =1 MHz, VBW=3 MHz when above 1 GHz, Start=30MHz, Stop= 10th harmonic. Band Edge Requirements: In the 1 MHz bands immediately outside and adjacent to the frequency block, a resolution bandwidth of at least 1 percent of the emission bandwidth of the fundamental emission of the transmitter may be employed to measure the out of band Emissions.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.



6.5 Field strength of spurious radiation measurement

between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB) Test Instruments: Refer to section 5.9 for details	o.o Ticia strength or sp	urious radiation measurement
Limit: LTE Band 2 & 4 & 5 & 12 & 13 & 17 & 66 & 71: The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10 logns(P) dB (13 dBm). Below 1GHz Test setup: 1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency. ER P / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) – Cable Loss (dB) Test Instruments: Refer to section 5.9 for details	Test Requirement:	· · · · · · · · · · · · · · · · · · ·
Test Procedure: 1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT. 3. The frequency was measured at a m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB) Test Instruments: Refer to section 5.9 for details	Test Method:	ANSI/TIA-603-D 2010
Above 1GHz Test Procedure: 1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB) Test Instruments: Refer to section 5.9 for details	Limit:	The power of any emission outside a licensee's frequency block shall be attenuated below the transmitter power (P) in watts by at least 43 + 10
Test Procedure: 1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB) Test Instruments: Refer to section 5.9 for details	Test setup:	Camera Antenna Tower (Turntable) Ground Reference Plane Generator Monitor Power Amplifier
conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable Loss (dB) Test Instruments: Refer to section 5.9 for details		AE EUT Ground Reference Plane
	Test Procedure:	 conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. 2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. 3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. 4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) - Cable
T	Test Instruments:	Refer to section 5.9 for details
l est mode: Refer to section 5.3 for details.	Test mode:	Refer to section 5.3 for details.





Test results:	Passed

Measurement Data:

LTE Band 2 part:

	LTE Band 2, WB: 1.4MHz				
	R	B size 1 & RB offset ()		
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MITIZ)	Polarization	Level (dBm)	Limit (ubin)	Result	
		Lowest Channel			
3701.40	Vertical	-49.71			
5552.10	V	-32.10			
7402.00	V	-38.96	-13.00	Pass	
3701.40	Horizontal	-50.68	-13.00	Pass	
5552.10	Н	-33.12			
7402.00	Н	-38.37			
		Middle Channel			
3760.00	Vertical	-49.67			
5640.00	V	-32.16		Descr	
7520.00	V	-38.47	12.00		
3760.00	Horizontal	-50.76	-13.00	Pass	
5640.00	Н	-33.08			
7520.00	Н	-38.45			
		Highest Channel			
3816.60	Vertical	-49.53			
5724.90	V	-32.08			
7633.20	V	-38.47	-13.00	Desa	
3816.60	Horizontal	-50.76		Pass	
5724.90	Н	-33.04			
7633.20	Н	-38.46			

Note:

The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report. For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LTE Band 2, WB: 20MHz				
	R	B size 1 & RB offset (0		
Fraguency (MUz)	Spurious	Emission	Limit (dDm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
		Lowest Channel			
3720.00	Vertical	-49.82			
5580.00	V	-32.25			
7440.00	V	-38.89	-13.00	Pass	
3720.00	Horizontal	-50.76	-13.00	Fd55	
5580.00	Н	-33.81			
7440.00	Н	-38.79			
		Middle Channel			
3760.00	Vertical	-49.48		Pass	
5640.00	V	-32.75			
7520.00	V	-38.76	-13.00		
3760.00	Horizontal	-50.46	-13.00		
5640.00	Н	-33.47			
7520.00	Н	-38.83			
		Highest Channel			
3800.00	Vertical	-49.76			
5700.00	V	-32.62	-13.00 Pass		
7600.00	V	-38.79		Door	
3800.00	Horizontal	-50.89		Pass	
5700.00	Н	-33.12			
7600.00	Н	-38.76			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 4 part:

	LTE Band 4, WB: 1.4MHz				
	RI	B size 1 & RB offset (0		
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
riequency (Minz)	Polarization	Level (dBm)	Limit (dbiii)	Result	
		Lowest Channel			
3421.40	Vertical	-45.06			
5132.10	V	-35.51			
6842.80	V	-37.86	-13.00	Pass	
3421.40	Horizontal	-47.85	-13.00	Fa55	
5132.10	Н	-39.91			
6842.80	Н	-38.53			
		Middle Channel			
3465.00	Vertical	-45.16			
5197.50	V	-35.03			
6930.00	V	-37.79	-13.00		
3465.00	Horizontal	-47.96	-13.00	Pass	
5197.50	Н	-39.37			
6930.00	Н	-38.43			
		Highest Channel			
3508.60	Vertical	-45.12			
5262.90	V	-35.53	-13.00 Pas		
7017.20	V	-37.86		Door	
3508.60	Horizontal	-47.85		Pass	
5262.90	Н	-39.87			
7017.20	Н	-38.46			

Note:

The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report. For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LTE Band 4, WB: 20MHz				
	RI	B size 1 & RB offset 0)		
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result	
		Lowest Channel			
3440.00	Vertical	-45.92			
5160.00	V	-35.76			
6880.00	V	-37.89	-13.00	Pass	
3440.00	Horizontal	-47.08	-13.00	Fa55	
5160.00	Н	-39.43			
6880.00	Н	-38.38			
		Middle Channel			
3465.00	Vertical	-47.47			
5197.50	V	-36.89		Davis	
6930.00	V	-37.53	-13.00		
3465.00	Horizontal	-47.84	-13.00	Pass	
5197.50	Н	-39.46			
6930.00	Н	-38.62			
		Highest Channel			
3490.00	Vertical	-46.71			
5235.00	V	-36.89	-13.00 Pass		
6980.00	V	-37.64		Door	
3490.00	Horizontal	-47.93		Pass	
5235.00	Н	-36.86			
6980.00	Н	-38.61			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 5 part:

	LTE Band 5, WB: 1.4MHz				
	R	B size 1 & RB offset ()		
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MH2)	Polarization	Level (dBm)	Limit (ubin)	Result	
		Lowest Channel			
1649.40	Vertical	-57.53			
2474.10	V	-49.35			
3298.80	V	-49.92	-13.00	Pass	
1649.40	Horizontal	-55.98	-13.00	Fa55	
2474.10	Н	-45.16			
3298.80	Н	-48.35			
		Middle Channel			
1673.00	Vertical	-57.26			
2509.50	V	-49.21		Pass	
3346.00	V	-49.83	-13.00		
1673.00	Horizontal	-56.24	-13.00	Fa55	
2509.50	Н	-45.46			
3346.00	Н	-48.57			
		Highest Channel			
1696.60	Vertical	-57.38			
2544.90	V	-49.56	-13.00		
3393.20	V	-49.68		Door	
1696.60	Horizontal	-56.73		Pass	
2544.90	Н	-45.81			
3393.20	Н	-48.69			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LT	E Band 5, WB: 10MH	lz	
	R	B size 1 & RB offset	0	
Fraguenov (MHz)	Spurious	Emission	Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1658.00	Vertical	-57.53		
2487.00	V	-49.36		
3316.00	V	-49.91	-13.00	Pass
1658.00	Horizontal	-56.87	-13.00	Fd55
2487.00	Н	-45.63		
3316.00	Н	-48.67		
		Middle Channel		
1673.00	Vertical	-57.64		Davis
2509.50	V	-49.86		
3346.00	V	-49.87	42.00	
1673.00	Horizontal	-56.72	-13.00	Pass
2509.50	Н	-46.12		
3346.00	Н	-48.73		
		Highest Channel		
1688.00	Vertical	-57.58		
2532.00	V	-49.26		
3376.00	V	-49.82	40.00	Dana
1688.00	Horizontal	-56.38	-13.00	Pass
2532.00	Н	-45.92		
3376.00	Н	-48.97		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 12 part:

	LTE	E Band 12, WB: 1.4M	Hz	
	R	B size 1 & RB offset	0	
Fraguency (MHz)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1399.40	Vertical	-58.79		
2099.10	V	-41.78		
2798.80	V	-53.32	-13.00	Pass
1399.40	Horizontal	-50.88	-13.00	Fd55
2099.10	Н	-44.50		
2798.80	Н	-52.87		
		Middle Channel		
1415.00	Vertical	-58.64		
2122.50	V	-41.83		Pass
2830.00	V	-53.64	-13.00	
1415.00	Horizontal	-50.92	-13.00	
2122.50	Н	-44.86		
2830.00	Н	-52.67		
		Highest Channel		
1430.60	Vertical	-58.89		
2145.90	V	-41.64	-13.00 Pa	
2861.20	V	-53.37		Door
1430.60	Horizontal	-50.91		Pass
2145.90	Н	-44.56		
2861.20	Н	-52.87		

Note:

^{1.}

The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report. For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



	LT	E Band 12, WB: 10M	Нz	
	R	B size 1 & RB offset (0	
Fraguency (MHz)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1408.00	Vertical	-57.83		
2112.00	V	-41.93		
2816.00	V	-53.66	-13.00	Pass
1408.00	Horizontal	-50.89	-13.00	Pass
2112.00	Н	-44.38		
2816.00	Н	-52.87		
		Middle Channel		
1415.00	Vertical	-58.39		
2122.50	V	-41.87		Pass
2830.00	V	-53.68	42.00	
1415.00	Horizontal	-50.43	-13.00	
2122.50	Н	-44.79		
2830.00	Н	-52.94		
		Highest Channel		
1422.00	Vertical	-57.89		
2133.00	V	-41.67	-13.00	
2844.00	V	-53.82		
1422.00	Horizontal	-50.67		Pass
2133.00	Н	-44.89		
2844.00	Н	-52.38		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 13 part:

_	LT	E Band 13, WB: 5MH	z	
	R	B size 1 & RB offset (0	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result
Frequency (Wiriz)	Polarization	Level (dBm)	Lilliit (dBill)	Result
		Lowest Channel		
1559.00	Vertical	-57.62	-40.00	
2338.50	V	-48.17		
3118.00	V	-50.37		Pass
1559.00	Horizontal	-54.39	-13.00	Fd55
2338.50	Н	-49.44		
3118.00	Н	-50.76		
		Middle Channel		
1564.00	Vertical	-57.68	-40.00	
2346.00	V	-48.26		
3128.00	V	-50.37		Pass
1564.00	Horizontal	-54.46	-13.00	Pass
2346.00	Н	-49.57		
3128.00	Н	-50.89		
		Highest Channel		
1569.00	Vertical	-54.68	-40.00	
2353.50	V	-49.83	-13	
3138.00	V	-50.37		Pass
1569.00	Horizontal	-54.49		Pass
2353.50	Н	-49.68		
3138.00	Н	-50.47		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 13, WB: 10MHz				
	RI	B size 1 & RB offset (0	
Fraguenov (MHz)	Spurious Emission		Linesit (alDine)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
Middle Channel				
1564.00	Vertical	-57.83		
2346.00	V	-48.37		
3128.00	V	-50.83	12.00	Door
1564.00	Horizontal	-54.91	-13.00	Pass
2346.00	Н	-49.87		
3128.00	Н	-50.89		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 17 part:

	LT	E Band 17, WB: 5MH	z	
	R	B size 1 & RB offset ()	
Fraguency (MUz)	Spurious Emission		Limit (dDm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Kesuit
		Lowest Channel		
1413.00	Vertical	-58.47		
2119.50	V	-49.11		
2826.00	V	-53.64	-13.00	Pass
1413.00	Horizontal	-56.35	-13.00	Pass
2119.50	Н	-45.25		
2826.00	Н	-53.28		
Middle Channel				
1420.00	Vertical	-58.56		
2130.00	V	-49.37		
2840.00	V	-53.48	-13.00	Pass
1420.00	Horizontal	-56.38	-13.00	Pass
2130.00	Н	-45.29		
2840.00	Н	-53.37		
Highest Channel				
1427.00	Vertical	-58.76		
2140.50	V	-49.26		
2854.00	V	-53.38	12.00	Door
1427.00	Horizontal	-56.74	-13.00	Pass
2140.50	Н	-45.38		
2854.00	Н	-53.79		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 17, WB: 10MHz					
	RI	B size 1 & RB offset 0)		
Fragues ov (MHz)	Spurious Emission		Limit (dDm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Resuit	
	Lowest Channel				
1418.00	Vertical	-58.36			
2127.00	V	-49.19			
2836.00	V	-53.75	-13.00	Pass	
1418.00	Horizontal	-56.38	-13.00	Pass	
2127.00	Н	-45.39			
2836.00	Н	-53.84			
Middle Channel					
1420.00	Vertical	-58.49			
2130.00	V	-49.83			
2840.00	V	-53.57	-13.00	Pass	
1420.00	Horizontal	-56.84	-13.00	Pass	
2130.00	Н	-45.89			
2840.00	Н	-53.37			
Highest Channel					
1422.00	Vertical	-59.94			
2133.00	V	-49.68			
2844.00	V	-53.46	12.00	Door	
1422.00	Horizontal	-56.81	-13.00	Pass	
2133.00	Н	-45.28			
2844.00	Н	-53.82			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 66 part:

	LTI	E Band 66, WB: 1.4M	Hz		
	R	B size 1 & RB offset	0		
Гто «о » о (МП I=)	Spurious Emission		Limit (dDm)	Desult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
	Lowest Channel				
3421.40	Vertical	-46.17			
5132.10	V	-34.67			
6842.80	V	-39.86	-13.00	Dana	
3421.40	Horizontal	-49.10	-13.00	Pass	
5132.10	Н	-41.88			
6842.80	Н	-39.93			
	Middle Channel				
3490.00	Vertical	-46.38			
5235.00	V	-34.86			
6980.00	V	-39.87	42.00	Pass	
3490.00	Horizontal	-49.26	-13.00	Pass	
5235.00	Н	-41.92			
6980.00	Н	-39.47			
Highest Channel					
3558.60	Vertical	-46.24			
5337.90	V	-34.72]		
7117.20	V	-39.92	12.00	Door	
3558.60	Horizontal	-49.16	-13.00	Pass	
5337.90	Н	-41.93			
7117.20	Н	-39.96			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 66, WB: 20MHz					
	R	B size 1 & RB offset (0		
Гто жиз ж ом (МП I=)	Spurious Emission		Limit (dPm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
	Lowest Channel				
3440.00	Vertical	-46.42			
5160.00	V	-34.89			
6880.00	V	-39.62	-13.00	Door	
3440.00	Horizontal	-49.38	-13.00	Pass	
5160.00	Н	-41.89			
6880.00	Н	-39.66			
	Middle Channel				
3490.00	Vertical	-46.72			
5235.00	V	-35.38			
6980.00	V	-39.67	-13.00	Pass	
3490.00	Horizontal	-49.56	-13.00	Pass	
5235.00	Н	-41.61			
6980.00	Н	-39.74			
Highest Channel					
3540.00	Vertical	-46.89			
5310.00	V	-34.86			
7080.00	V	-39.67	42.00	Desc	
3540.00	Horizontal	-49.52	-13.00 Pass	Pass	
5310.00	Н	-41.97			
7080.00	Н	-38.52			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.





LTE Band 71 part:

ETE Bana 71 part.		E Band 71, WB: 5MH	z		
	RB size 1 & RB offset 0				
	Spurious Emission				
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
	Lowest Channel				
1346.00	Vertical	-53.62			
2019.00	V	-43.37			
2692.00	V	-52.87	42.00	Pass	
1346.00	Horizontal	-52.14	-13.00		
2019.00	Н	-42.87			
2692.00	Н	-53.64			
Middle Channel					
1361.00	Vertical	-53.67			
2041.50	V	-43.56			
2722.00	V	-52.17	12.00	Pass	
1361.00	Horizontal	-52.36	-13.00	Fd55	
2041.50	H	-42.89			
2722.00	Н	-53.67			
Highest Channel					
1376.00	Vertical	-53.48			
2064.00	V	-43.26			
2752.00	V	-52.67	-13.00	Pass	
1376.00	Horizontal	-52.36	-13.00	Fa55	
2064.00	Н	-42.89			
2752.00	Н	-53.64			

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



LTE Band 71, WB: 20MHz				
	RB size 1 & RB offset 0			
Fraguenov (MUz)	Spurious Emission		Limit (dDm)	Dooult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
		Lowest Channel		
1331.00	Vertical	-53.64		
1996.50	V	-43.92		
2662.00	V	-52.89	-13.00	Pass
1331.00	Horizontal	-52.64	-13.00	Fd55
1996.50	Н	-42.65		
2662.00	Н	-53.49		l
Middle Channel				
1361.00	Vertical	-53.21		
2041.50	V	-43.52		
2722.00	V	-52.97	12.00	Pass
1361.00	Horizontal	-52.46	13.00 Pa	Pass
2041.50	Н	-42.36		
2722.00	Н	-53.78		
Highest Channel				
1391.00	Vertical	-53.86		
2086.50	V	-43.95		
2782.00	V	-52.89	42.00	Door
1391.00	Horizontal	-52.67	-13.00 Pass	Pass
2086.50	Н	-42.98		
2782.00	Н	-53.72		

Note:

^{1.} The emission levels of below 1 GHz are 20 dB lower than the limit so not show in this report.

^{2.} For above 1 GHz, all test modes were performed, and just the worst case shown in the report.



6.6 Frequency stability V.S. Temperature measurement

Test Requirement:	Part 22.355, Part 24.235, Part 27.54, Part 2.1055(a)(1)(b)	
Test Method:	ANSI/TIA-603-D 2010	
Limit:	±2.5ppm Within Authorized Band	
Test setup:	SS BUT Divider Temperature & Humidity Chamber Power Source	
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached 	
Test Instruments:	Refer to section 5.9 for details	
Test mode:	Refer to section 5.3 for details	
Test results:	Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.	



6.7 Frequency stability V.S. Voltage measurement

Test Requirement:	Part 22.355, Part 24.235, Part 27.54, Part 2.1055(d)(2)
Test Method:	ANSI/TIA-603-D 2010
Limit:	±2.5ppm Within Authorized Band
Test setup:	SS EUT Divider Temperature & Humidity Chamber
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.9 for details
Test mode:	Refer to section 5.3 for details
Test results:	Refer to FCC ID: ZMONL668AM00, Report No.: FG8O1914-01B.